



32V PNP MEDIUM POWER TRANSISTOR IN SOT89

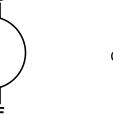
Features

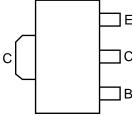
- BV_{CEO} > -32V
- I_C = -2A High Continuous Current
- Low Saturation Voltage V_{CE(sat)} < -800mV @ -2A
- Complementary NPN Type: 2DD1766
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT89
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)







Top View

Device Symbol

Pin Out - Top View

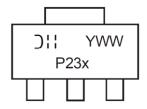
Ordering Information (Note 4)

Part Number	Status	Compliance	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
2DB1188P-13	Obsolete	Standard	P23P	13	12	2,500
2DB1188Q-13	Active	Standard	P23Q	13	12	2,500
2DB1188Q-13R	Active	Standard	P23Q	13	12	4,000
2DB1188R-13	Active	Standard	P23R	13	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



P23x = Product Type Marking Code Where P23P = 2DB1188P P23Q = 2DB1188Q P23R = 2DB1188R

☐ = Manufacturers' Code Marking YWW = Date Code Marking

Y or \overline{Y} = Last Digit of Year (ex: 1 = 2021)

WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-32	V
Emitter-Base Voltage	V_{EBO}	-6	V
Continuous Collector Current	Ιc	-2	А
Peak Pulse Collector Current	I _{CM}	-3	А
Base Current	lΒ	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{0JL}	19	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

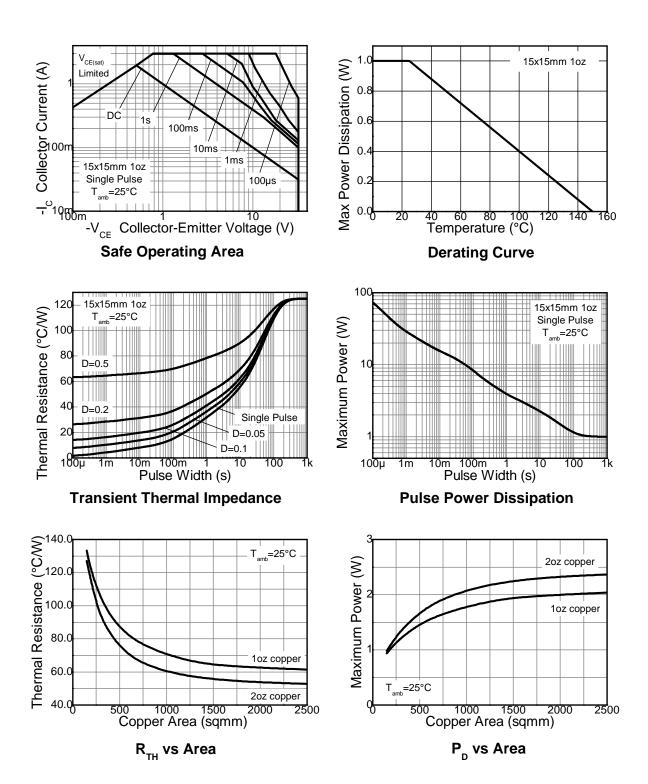
Notes:

^{5.} For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

^{6.} Thermal resistance from junction to solder-point (on the exposed collector pad).



Thermal Characteristics and Derating Information



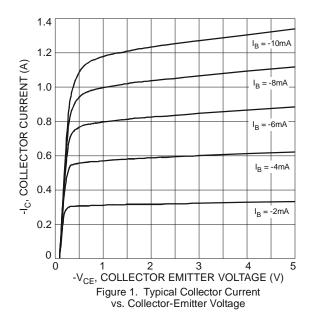


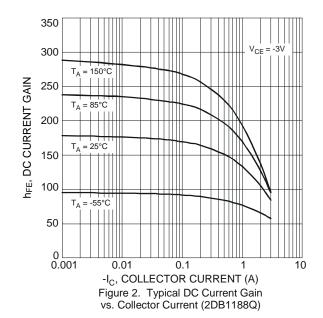
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic			Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)							
Collector-Base Breakdown Voltage		BV _{CBO}	-40	_	_	V	I _C = -100μA
Collector-Emitter Breakdown \	/oltage	BV _{CEO}	-32	_	_	V	I _C = -10mA
Emitter-Base Breakdown Volta	age	BV _{EBO}	-6	_	_	V	$I_E = -100 \mu A$
Collector Cutoff Current		I _{CBO}	_	_	-100	nA	V _{CB} = -20V
Emitter Cutoff Current		I _{EBO}	_	_	-100	nA	V _{EB} = - 5V
ON CHARACTERISTICS (No	te 7)						
Collector-Emitter Saturation Voltage		V _{CE(sat)}		-0.35	-0.8	V	$I_C = -2A$, $I_B = -0.2A$
	2DB1188P		82		180		V _{CE} = -3V, I _C = -0.5A
DC Current Gain	2DB1188Q	h _{FE}	120		270	_	
	2DB1188R		180		390		
SMALL SIGNAL CHARACTE	RISTICS						
Current Gain-Bandwidth Product		f⊤		120	_	MHz	$V_{CE} = -5V, I_{C} = -0.1A,$ f = 30MHz
Output Capacitance		C _{obo}		20	_	pF	$V_{CB} = -10V$, $f = 1MHz$

Note:

7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.







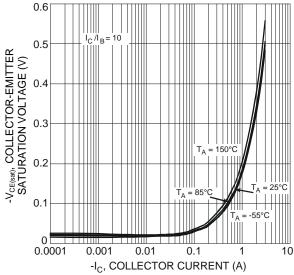


Figure 3. Typical Collector-Emitter Saturation Voltage vs. Collector Current

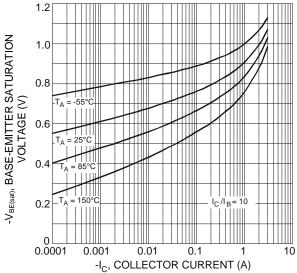


Figure 5. Typical Base-Emitter Saturation Voltage vs. Collector Current

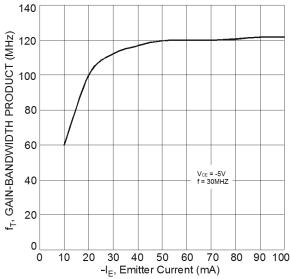


Figure 7. Typical Gain-Bandwidth Product vs. Emitter Current

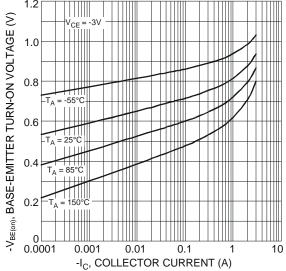


Figure 4. Typical Base-Emitter Turn-On Voltage vs. Collector Current

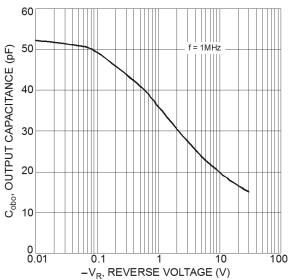


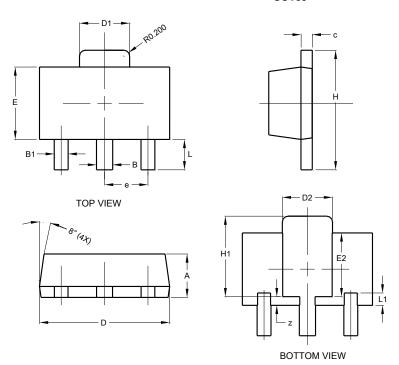
Figure 6. Typical Output Capacitance Characteristics



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

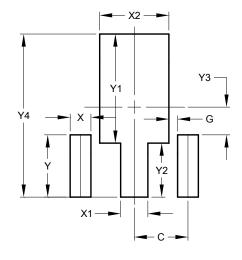


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
E	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	1	1	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value			
Dilliensions	(in mm)			
С	1.500			
G	0.244			
Х	0.580			
X1	0.760			
X2	1.933			
Υ	1.730			
Y1	3.030			
Y2	1.500			
Y3	0.770			
Y4	4.530			



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